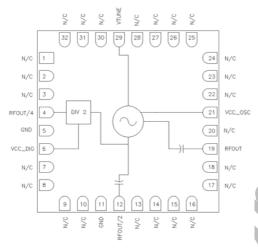


RFVC1843A

10.19GHz to 11.33GHz MMIC VCO with Fo/2 and Fo/4 Outputs

RFMD's RFVC1843A is a 5V InGaP MMIC VCO with an integrated frequency divider providing additional Fo/2 and Fo/4 outputs. With an Fo frequency range of 10.19GHz to 11.33GHz its monolithic structure provides excellent temperature, shock, and vibration performance. Output power (Fo) is +7dBm and is flat across the tuning voltage range of 1.5V to 14.5V. Phase noise is typically -114dBc/Hz at 100kHz offset. The device operates from a low supply current of 275mA which can be further reduced to 215mA by disabling the divider functions if not required. The RFVC1843A is available in a low cost 5mm x 5mm surface mount plastic overmolded QFN outline.



Functional Block Diagram

Ordering Information

RFVC1843AS2	Sample bag with 2 pieces		
RFVC1843ASB	Sample bag with 5 pieces		
RFVC1843ASQ	Bag with 25 pieces		
RFVC1843ASR	Bag with 100 pieces		
RFVC1843ATR7	7" Reel with 750 pieces		

RFVC1843APCBA-410 Evaluation Board



Package: Plastic QFN, 32-pin, 5mm x 5mm x 0.85mm

Features

- Multiple Frequency Outputs
 - Fo: 10.19GHz to 11.33GHz
 - Fo/2: 5.10GHz to 5.67GHz
 - Fo/4: 2.55GHz to 2.83GHz
- No External Resonator Required
- Integrated Frequency Divider
- Phase Noise: -114dBc/Hz at 100kHz Offset
- Flat Output Power Over Frequency Tuning Range 1.5V to 14.5V
 - Fo: 7dBm
 - Fo/2: 8dBm
 - Fo/4: -2dBm
- Low Power Consumption
 - 5V/275mA (Divider On)
 - 5V/215mA (Divider Off)
- 32-Lead 5mm x 5mm Plastic Overmolded QFN

Applications

- Point-to-Point Radio
- Point-to-Multipoint Radio
- Satellite Communications
- Test Equipment
- Military
- Aerospace



Absolute Maximum Ratings

Parameter	Rating	Unit
V _{CC_OSC} , V _{CC_DIG}	+5.5	V
V _{TUNE}	0 to +14	V
Junction Temperature (T _J)	135	°C
Continuous P _{DISS} (T = 85°C) (derate 37mW/°C above T = 85°C)	1.65	W
Storage Temperature	-65 to +150	°C
Operating Temperature	-40 to +85	°C
ESD Sensitivity (HBM)	Class 1A	



Caution! ESD sensitive device.



RFMD Green: RoHS compliant per EU Directive 2011/65/EU, halogen free per IEC 61249-2-21, <1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony solder.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

Nominal Operating Parameters

Parameter Specification Unit Condition	Specification					
	Condition					
Electrical Specifications					V _{CC} = 5V, T _A = +25°C	
Operating Frequency						
Fo	10.19		11.33	GHz		
Fo/2	5.10		5.67	GHz		
Fo/4	2.55		2.83	GHz		
Output Power						
Fo		7		dBm		
Fo/2		8		dBm		
Fo/4		-2		dBm		
SSB Phase Noise						
10kHz offset at RF _{OUT}		-90	-80	dBc/Hz		
100kHz offset at RF _{OUT}		-114	-108	dBc/Hz		
Tune Voltage	1.5		14.5	V		
Supply Current						
V _{CC_OSC}	•	215		mA		
V _{CC_DIG}		60		mA		
Tune Port Leakage Current		10		μΑ		
Output Return Loss		5		dB		

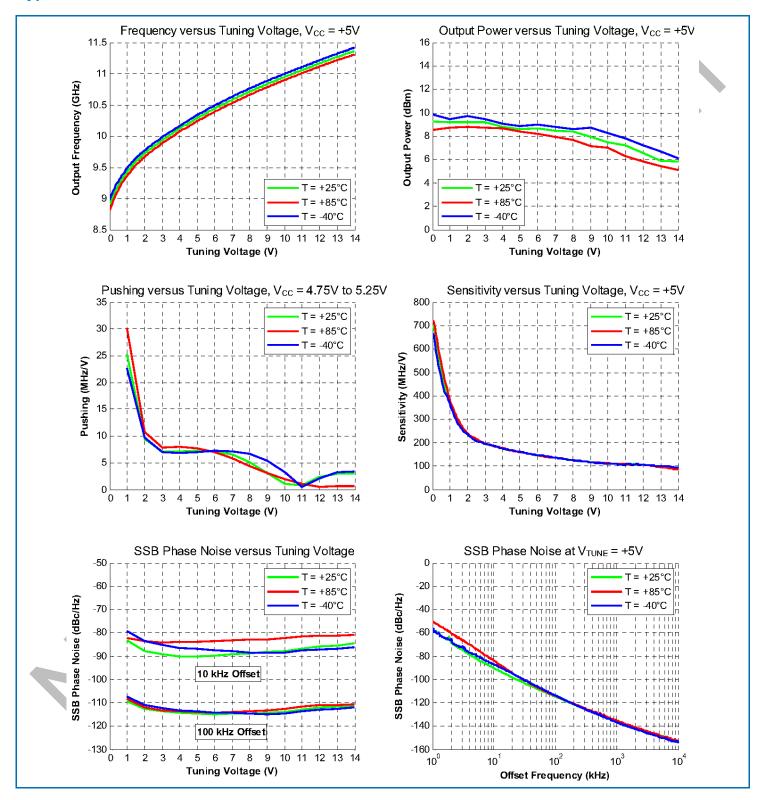
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Parameter	Spo	Specification		Unit	Condition
raiailletei	Min	Тур	Max		Condition
Electrical Specifications (continued)					
Harmonics/Sub-harmonics					Measured with RF probes at package, not at SMA connections on EVB
1/2		50		dBc	
3/2		40		dBc	*.
2 nd		10		dBc	
3 rd		18		dBc	
Pulling (into a 2.0:1 VSWR)		5		MHz pp	
Pushing		10		MHz/V	
Frequency Drift Rate		0.9		MHz/°C	

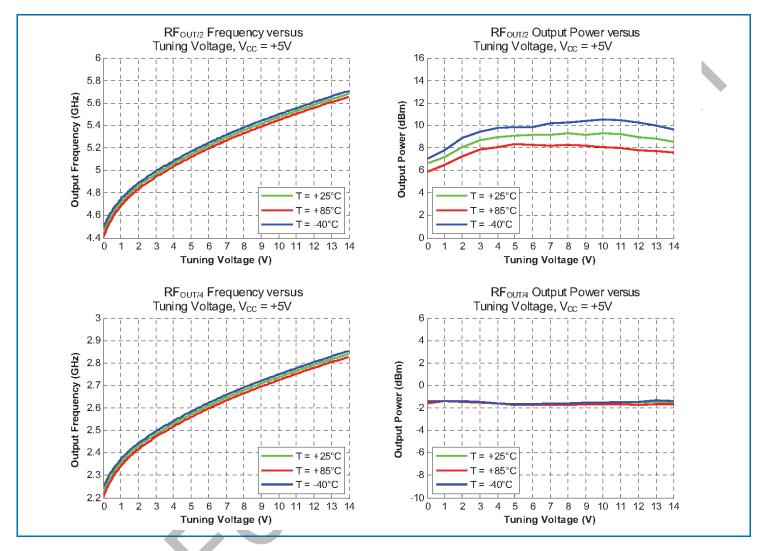


Typical Performance





Typical Performance (continued)





Pin Names and Descriptions

Pin	Name	Description	Interface Schematic
1-3	N/C	No internal connection.	
4	RFOUT/4	VCO RF output at Fo/4. Externally DC-blocked.	SV RFOUT/4
5	GND	Connect to PCB ground.	GND =
6	VCC_DIG	Supply voltage input for the integrated frequency divider. Typical +5V. Ground this pin to disable digital divider and reduce current consumption by 65mA.	VCC_DIG
7-10	N/C	No internal connection.	
11	GND	Connect to PCB ground.	See Pin 5 interface schematic
12	RFOUT/2	VCO RF output at Fo/2. Internally DC-blocked.	RFOUT/2 •—
13-18	N/C	No internal connection.	
19	RFOUT	VCO RF output at Fo. Internally DC-blocked.	RFOUT 0
20	N/C	No internal connection.	
21	VCC_OSC	Supply voltage input for the VCO. Typical +5V.	VCC_OSC



Pin Names and Descriptions (continued)

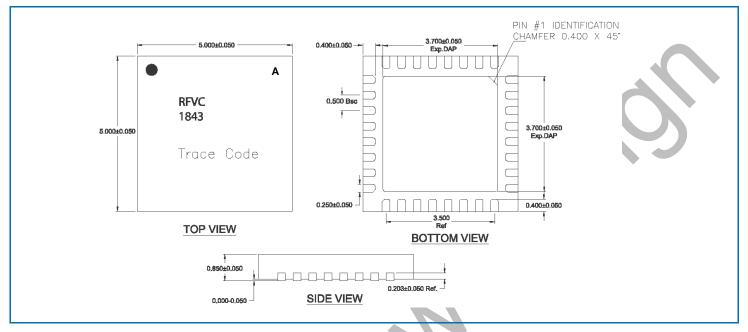
Pin	Name	Description	Interface Schematic		
22-28	N/C	No internal connection.			
29	VTUNE	VCO control voltage input.	VTUNE		
30-32	N/C	No internal connection.			
PKG BASE	GND	Connect to PCB ground.	See Pin 5 interface schematic		



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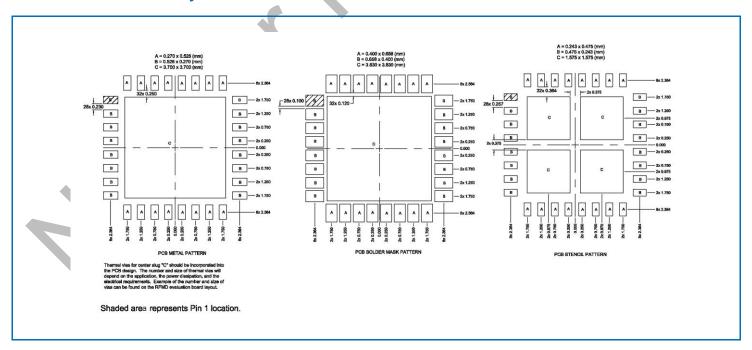
Package Drawing (Dimensions in millimeters)



Notes:

- 1. Dimensions are for reference only.
- 2. Package body material: Plastic.
- 3. Lead and paddle plating: 8µm minimum of Sn over Cu leadframe.

Recommended PCB Layout

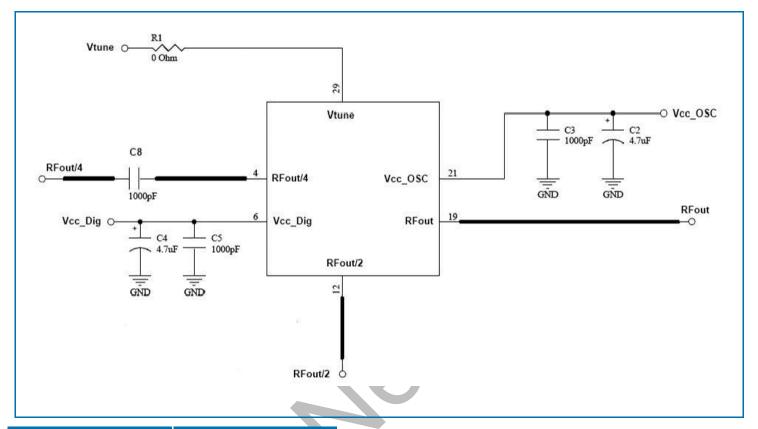


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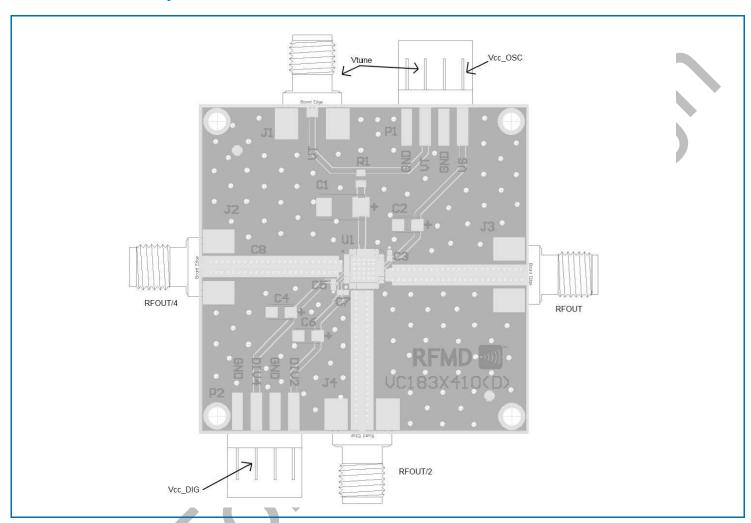
Sample Application Circuit Schematic



Bias Conditions	Output
V _{CC_OSC} = 5V	F _{OUT} = 10.4GHz
V _{CC_DIG} = 5V	F _{OUT/2} = 5.2GHz
$V_{TUNE} = 5V$	F _{OUT/4} = 2.6GHz



Evaluation Board Layout



Evaluation Board Bill of Materials (BOM)

Item	Description
U1	RFVC1843A VCO
C3, C5, C7, C8	1000pF Capacitor, 0402 Package
C2, C4, C6	4.7μF Tantalum Capacitor
C1	68µF Tantalum Capacitor
R1	0Ω Resistor, 0603 Package
P1, P2	4-PIN DC connector
J1, J2, J3, J4	PCB mount SMA connector
PCB	VC183x410(D)